

# 7.5 inch E-paper Display Series



Dalian Good Display Co., Ltd.





# **Product Specifications**





Customer	Standard
Description	7.5" E-PAPER DISPLAY
Model Name	GDEH075Z90R
Date	2020/07/15
Revision	1.0

D	Design Engineering						
Approval	Approval Check Design						
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Version	Content	Date	Producer
1.0	New release	2020/07/15	
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# **1. General Description**

### **1.1 Overview**

GDEH075Z90R is an Active Matrix Electrophoretic Display (AMEPD), with interface and a reference system design. The 7.5" active area contains528×880 pixels, and has 1-bit B/W/R full display capabilities. An integrated circuit contains gate buffer, source buffer, interface, timing control logic, oscillator, DC-DC. SRAM.LUT, VCOM and border are supplied with each panel.

## **1.2 Features**

- 528×880 pixels display
- High contrast
- High reflectance
- Ultra wide viewing angle
- Ultra low power consumption
- Pure reflective mode
- Bi-stable display
- Commercial temperature range
- Landscape, portrait modes
- Hard-coat antiglare display surface
- Ultra Low current deep sleep mode
- On chip display RAM
- Low voltage detect for supply voltage
- High voltage ready detect for driving voltage
- Internal temperature sensor
- 10-byte OTP space for module identification
- Waveform stored in On-chip OTP
- Serial peripheral interface available
- On-chip oscillator
- On-chip booster and regulator control for generating VCOM, Gate and Source driving voltage

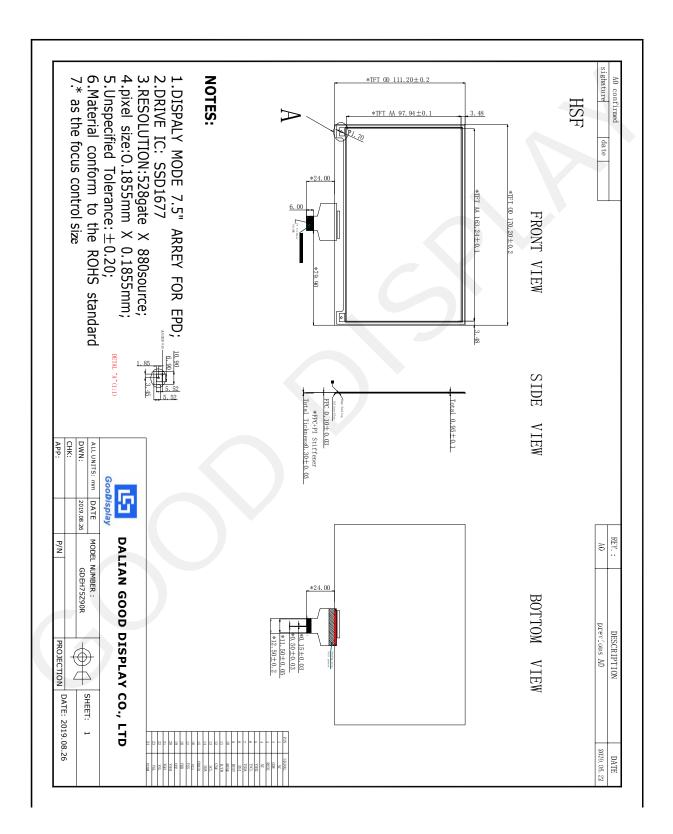
• I2C signal master interface to read external temperature sensor/built-in temperature sensor

## **1.3 Mechanical Specifications**

Parameter	Parameter Specifications		Remark
Screen Size	Screen Size 7.5		
Display Resolution	880(H)×528(V)	Pixel	Dpi:137
Active Area	163.24(H)×97.94(V)	mm	
Pixel Pitch	Pixel Pitch 0.1855×0.1855		
Pixel Configuration	Rectangle		
Outline Dimension	170.2(H)×111.2 (V) ×1.25(D)	mm	
Weight	31±0.2	g	



# **1.4 Mechanical Drawing of EPD module**



# **1.5 Input/Output Terminals**

Pin #	Single	Description	Remark
1	NC	No connection and do not connect with other NC pins	Keep Open
2	GDR	N-Channel MOSFET Gate Drive Control	
3	RESE	Current Sense Input for the Control Loop	
4	NC	No connection and do not connect with other NC pins e	Keep Open
5	VSH2	Positive Source driving voltage	
6	TSCL	I2C Interface to digital temperature sensor Clock pin	
7	TSDA	I2C Interface to digital temperature sensor Date pin	
8	BS1	Bus selection pin	Note 1.5-5
9	BUSY	Busy state output pin	Note 1.5-4
10	RES #	Reset	Note 1.5-3
11	D/C #	Data /Command control pin	Note 1.5-2
12	CS #	Chip Select input pin	Note 1.5-1
13	SCL	serial clock pin (SPI)	
14	SDA	serial data pin (SPI)	
15	VDDIO	Power for interface logic pins	
16	VCI	Power Supply pin for the chip	
17	VSS	Ground	
18	VDD	Core logic power pin	
19	VPP	Power Supply for OTP Programming	
20	VSH1	Positive Source driving voltage	
21	VGH	Power Supply pin for Positive Gate driving voltage and VSH	
22	VSL	Negative Source driving voltage	
23	VGL	Power Supply pin for Negative Gate driving voltage, VCOM and VSL	
24	VCOM	VCOM driving voltage	

Note 1.5-1: This pin (CS#) is the chip select input connecting to the MCU. The chip is enabled for MCU communication: only when CS# is pulled LOW.

Note 1.5-2: This pin (D/C#) is Data/Command control pin connecting to the MCU. When the pin is pulled HIGH,

the data will be interpreted as data. When the pin is pulled LOW, the data will be interpreted as command.

Note 1.5-3: This pin (RES#) is reset signal input. The Reset is active low. Note 1.5-4: This pin (BUSY) is Busy state output pin. When Busy is High the operation of chip should not be interrupted and any commands should not be issued to the module. The driver IC will put Busy pin High when the

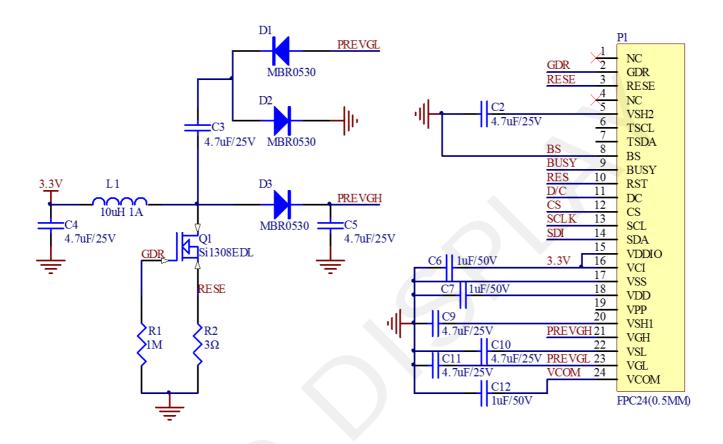
driver IC is working such as:

- Outputting display waveform; or
- Communicating with digital temperature sensor

Note 1.5-5: This pin (BS1) is for 3-line SPI or 4-line SPI selection. When it is "Low", 4-line SPI is selected. When it is "High", 3-line SPI (9 bits SPI) is selected.



# **1.6 Reference Circuit**



# **1.7 Matched Development Kit**

Our Development Kit designed for SPI E-paper Display aims to help users to learn how to use E-paper Display more easily. It can refresh black-white Epaper Display and three-color (black, white and red/Yellow) Good Display 's Epaper Display. And it is also added the functions of USB serial port, Raspberry Pi and LED indicator light ect.

DESPI Development Kit consists of the development board and the pinboard.

More details about the Development Kit, please click to the following link:

http://www.good-display.com/companyfile/Development-Board-8

### 2. Environmental

## 2.1 HANDLING, SAFETY AND ENVIROMENTAL REQUIREMENTS

#### WARNING

The display module should be kept flat or fixed to a rigid, curved support with limited bending along the long axis. It should not be used for continual flexing and bending. Handle with care. Should the display break do not touch any material that leaks out. In case of contact with the leaked material then wash with water and soap.

#### CAUTION

The display module should not be exposed to harmful gases, such as acid and alkali gases, which corrode electronic components.

Disassembling the display module can cause permanent damage and invalidate the warranty agreements.

IPA solvent can only be applied on active area and the back of a glass. For the rest part, it is not allowed.

Observe general precautions that are common to handling delicate electronic components. The glass can break and front surfaces can easily be damaged. Moreover the display is sensitive to static electricity and other rough environmental conditions.

#### Mounting Precautions

(1) It`s recommended that you consider the mounting structure so that uneven force (ex. Twisted stress) is not applied to the module.

(2) It's recommended that you attach a transparent protective plate to the surface in order to protect the EPD. Transparent protective plate should have sufficient strength in order to resist external force.

(3) You should adopt radiation structure to satisfy the temperature specification.

(4) Acetic acid type and chlorine type materials for the cover case are not desirable because the former generates corrosive gas of attacking the PS at high temperature and the latter causes circuit break by electro-chemical reaction.

(5) Do not touch, push or rub the exposed PS with glass, tweezers or anything harder than HB pencil lead. And please do not rub with dust clothes with chemical treatment. Do not touch the surface of PS for bare hand or greasy cloth. (Some cosmetics deteriorate the PS)

(6) When the surface becomes dusty, please wipe gently with absorbent cotton or other soft materials like chamois soaks with petroleum benzene. Normal-hexane is recommended for cleaning the adhesives used to attach the PS. Do not use acetone, toluene and alcohol because they cause chemical damage to the PS.

(7) Wipe off saliva or water drops as soon as possible. Their long time contact with PS causes deformations and color fading.

	Data sheet status
Product specification	The data sheet contains final product specifications.

#### Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and dose not form part of the specification.

#### Product Environmental certification

ROHS

#### REMARK

All The specifications listed in this document are guaranteed for module only. Post-assembled operation or component(s) may impact module performance or cause unexpected effect or damage and therefore listed specifications is not warranted after any Post-assembled operation.

# 2.2 Reliability test

	TEST	CONDITION	METHOD	REMARK
1	High-Temperature Operation	T=40°C , RH=35%RH , For 240Hr	IEC 60 068-2-2Bb	
2	Low-Temperature Operation	T = 0°C for 240 hrs	IEC 60 068-2-2Ab	
3	High-Temperature Storage	T=60°C RH=35% RH For 240Hr Test in white pattern	IEC 60 068-2-2Bb	1
4	Low-Temperature Storage	T = -25°C for 240 hrs Test in white pattern	IEC 60 068-2-2Ab	
5	High Temperature, High- Humidity Operation	T=40°C , RH=80%RH , For 168Hr	IEC 60 068-2-3CA	
6	High Temperature, High- Humidity Storage	T=50°C , RH=80%RH , For 240Hr Test in white pattern	IEC 60 068-2-3CA	
7	Temperature Cycle	-25°C(30min)~60°C(30min) , 50 Cycle Test in white pattern	IEC 60 068-2-14NB	
8	Package Vibration	1.04G,Frequency : 10~500Hz Direction : X,Y,Z Duration:1hours in each direction	Full packed for shipment	
9	Package Drop Impact	Drop from height of 100 cm on Concrete surface Drop sequence:1 corner, 3edges, 6face One drop for each.	Full packed for shipment	
10	UV exposure Resistance	765 W/m <sup>2</sup> for 168hrs,40°C	IEC 60068-2-5 Sa	
11	Electrostatic discharge	Machine model: +/-250V,0Ω,200pF	IEC61000-4-2	

Actual EMC level to be measured on customer application.

Note1 : Stay white pattern for storage and non-operation test.

Note2 : Operation is black/white/red pattern , hold time is 150S.

Note3 : The function, appearance, opticals should meet the requirements of the test

before and after the test. Note4 : Keep testing after 2 hours placing at 20°C-25°C.

# **3. Electrical Characteristics**

# **3.1 ABSOLUTE MAXIMUM RATING**

#### Table 3.1-1: Maximum Ratings

Symbol	Parameter	Rating	Unit	Humidity	Unit	Note
V <sub>CI</sub>	Logic supply voltage	-0.5 to +6.0	V	-	-	
T <sub>OPR</sub>	Operation temperature range	0 to 40	°C	45 to70	%	Normal use is recommended to refresh every 24 hours
-	Transportation temperature range	-25 to 60	°C	-	-	Note3.1-1
Tstg	Storage condition	0 to 40	°C	45 to70	%	Maximum storage time: 5 years
-	After opening the package	0 to 40	°C	45 to70	%	

Note 3.1-1: The transport time is within 10 days for  $-25^{\circ}C \sim 0^{\circ}C$  or  $40^{\circ}C \sim 60^{\circ}C$ Note 3.1-2 : When the three-color product is stored. The display screen should be kept white and face up. In addition, please be sure to refresh the e-paper every three months.

# **3.2 DC CHARACTERISTICS**

The following specifications apply for: VSS=0V, VCI=3.3V, TOPR=25°C.

Symbol	Parameter	<b>Test Condition</b>	Applicable pin	Min.	Тур.	Max.	Unit		
VCI	VCI operation voltage	-	VCI	2.2	3	3.7	V		
VIH	High level input voltage	-	SDA, SCL, CS#, D/C#,	0.8VDDIO	-	-	V		
VIL	Low level input voltage	-	RES#, BS1	-	-	0.2VDDIO	V		
VOH	High level output voltage	IOH = -100uA	BUSY,	0.9VDDIO	-	-	V		
VOL	Low level output voltage	IOL = 100uA		-	-	0.1VDDIO	V		
Iupdate	Module operating current	-	-	-		18	mA		
Isleep	Deep sleep mode	VCI=3.3V	-	-		2	uA		

#### **Table 3.2-1: DC Characteristics**

- The Typical power consumption is measured using associated 25°C waveform with following pattern transition: from horizontal scan pattern to vertical scan pattern. (Note 3.2-1)

- The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by Good Display.

- Vcom value will be OTP before in factory or present on the label sticker.

#### Note 3.2-1 The Typical power consumption

# 3.3 Serial Peripheral Interface Timing

**The following** gdYV**JZJ**V**Uh**]cbg<sup>·</sup>**U**dd`m**Z**cf. <sup>·</sup>J GG1 \$J ž<sup>·</sup>J 7=1 &"&J <sup>·</sup>hc<sup>·</sup>' "+J ž<sup>·</sup>HC DF 1 &)

#### Write mode

Symbol	Parameter	Min	Тур	Max	Unit
fSCL	SCL frequency (Write Mode)			20	MHz
tCSSU	Time CSB has to be low before the first rising edge of SCLK	20			ns
tCSHLD	Time CSB has to remain low after the last falling edge of SCLK	20			ns
tCSHIGH	Time CSB has to remain high between two transfers	100			ns
tSCLHIGH	Part of the clock period where SCL has to remain high	25			ns
tSCLLOW	Part of the clock period where SCL has to remain low	25			ns
tSISU	Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL	10			ns
tSIHLD	Time SI (SDA Write Mode) has to remain stable after the rising edge of SCL	40			ns

#### Read mode

Symbol	Parameter	Min	Тур	Max	Unit
fSCL	SCL frequency (Read Mode)			2.5	MHz
tCSSU	Time CSB has to be low before the first rising edge of SCLK	100			ns
tCSHLD	Time CSB has to remain low after the last falling edge of SCLK	50			ns
tCSHIGH	Time CSB has to remain high between two transfers	250			ns
tSCLHIGH	Part of the clock period where SCL has to remain high	180			ns
tSCLLOW	Part of the clock period where SCL has to remain low	180			ns
tSOSU	Time SO(SDA Read Mode) will be stable before the next rising edge of SCL		50		ns
tSOHLD	Time SO (SDA Read Mode) will remain stable after the falling edge of SCL		0		ns

Note: All timings are based on 20% to 80% of VDDIO-VSS

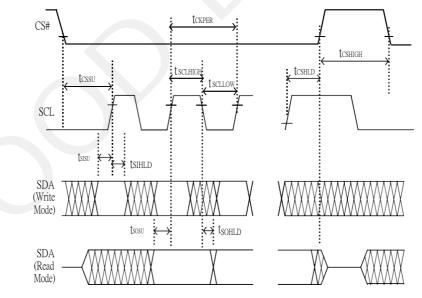


Figure 3.3-1: Serial peripheral interface characteristics

# **3.4 Power Consumption**

Parameter	Symbol	Conditions	ТҮР	Max	Unit	Remark
Panel power consumption during update	-	25°C		300	mAs	-
Deep sleep mode	-	25°C		2	uA	-

Mas=update average current × update time

### **3.5 MCU Interface**

### 3.5.1MCU interface selection

GDEH075Z90R can support 4-wire or 3-wire serial peripheral MCU interface, which is pin selectable by BS1 pin. The interface pin assignment for different MCU interfaces is shown in Table 3.5-1.

Note

- (1) L is connected to VSS
- (2) H is connected to VDDIO

#### Table 3.5-1: Interface pin assignment for different MCU interfaces

		Pin Name										
MCU Interface	BS1	RES#	CS#	<b>D/C</b> #	SCL	SDI	SDO					
4-wire serial peripheral interface (SPI)	L	Required	Required	Required	SCL	SDI	SDO					
3-wire serial peripheral interface (SPI) – 9 bits SPI	Н	Required	Required	L	SCL	SDI	SDO					

## 3.5.2 MCU Serial Peripheral Interface (4-wire SPI)

The 4-wire SPI consists of serial clock SCL, serial data input SDI, D/C# and CS#. The control pins status in 4-wire SPI in writing command/data is shown in Table 1.5-2 and the write procedure in 4-wire SPI is shown in Figure 1.5-1..

Function	SCL pin	SDI pin	D/C# pin	CS# pin
Write command	1	Command bit	L	L
Write data	1	Data bit	Н	L

Note:

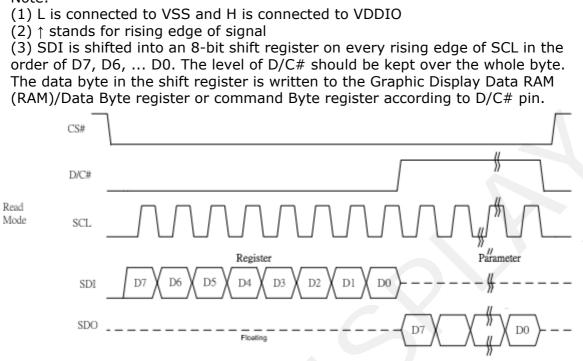


Figure 3.5-1: wire mode

In the read operation, after CS# is pulled low, the first byte sent is command byte, D/C# is pulled low. After command byte sent, the following byte(s) read are data byte(s), so D/C# bit is then pulled high. An 8-bit data will be shifted out on every clock falling edge. The serial data output SDO bit shifting sequence is D7, D6, to D0 bit. Figure 6-2 shows the read procedure in 4-wire SPI.

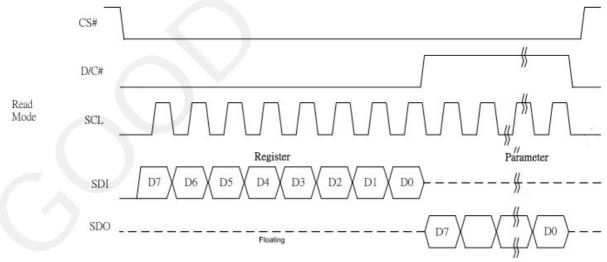


Figure 3.5-2: Read procedure in 4-wire SPI mode

### 3.5.3 MCU Serial Peripheral Interface (3-wire SPI)

The 3-wire SPI consists of serial clock SCL, serial data input SDI, and CS#. The operation is similar to 4- wire SPI while D/C# pin is not used and it must be tied to LOW. The control pins status in 3-wire SPI is shown in Table 3.5-3.

In the write operation, a 9-bit data will be shifted into the shift register on every clock rising edge. The bit shifting sequence is D/C# bit, D7 bit, D6 bit to D0 bit. The first bit is D/C# bit which determines the following byte is command or data. When D/C# bit is 0, the following byte is command. When D/C# bit is 1, the following byte is data. Table 3.5-3 shows the write procedure in 3-wire SPI

Function	SCL pin	SDI pin	D/C# pin	CS# pin
Write command	Ť	Command bit	Tie LOW	L
Write data	<b>↑</b>	Data bit	Tie LOW	L

Table 3.5-3 : Control pins status of 3-wire SPI

Note:

Write Mode

- (1) L is connected to VSS and H is connected to VDDIO
- (2)  $\uparrow$  stands for rising edge of signal

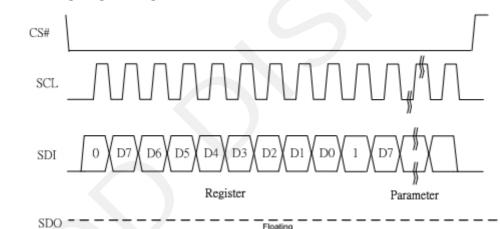
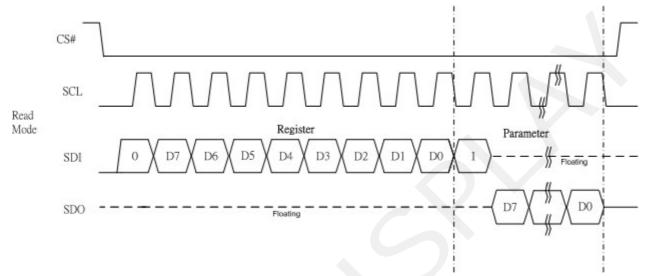


Figure 3.5-3: Write procedure in 3-wire SPI mode

In the read operation, serial data are transferred in the unit of 9 bits. After CS# pull low, the first byte is command byte, the D/C# bit is as 0 and following with the register byte. After command byte send, the following byte(s) are data byte(s), with D/C# bit is 1. After D/C# bit sending from MCU, an 8-bit data will be shifted out on every clock falling edge. The serial data output SDO bit shifting sequence is D7, D6, to D0 bit. Figure 7-4 shows the read procedure in 3-wire SPI.

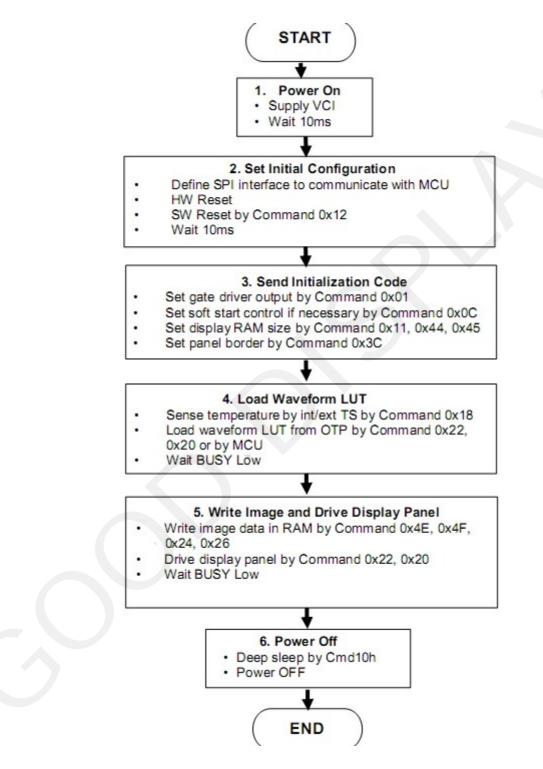






### 4. Typical Operating Sequence

## 4.1 Normal Operation Flow



# **5. COMMAND TABLE**

W#	D/C#	e 1	Hex	D	D6	D5	D4	D	D	2	D1		D0	Command	1	Description
	0		04	7 0	0	0	0	3	1	-	0		0		iving voltage	*
			04	A				Å		_			-	Control	ining formage	Set Source driving voltage A[7:0] = 41h [POR], VSH1 at 15V
	1			7	A6	A5	A4	3	A		A1		A2			B[7:0] = A8h [POR], VSH2 at 5V.
	1			B7	B6	B5	B4	B3	B		B1		B0			C[7:0] = 32h [POR], VSL at -15V
	1			C7	C6	C5	C4	C3	C		C1		C0			
[7] = 1, [SH2 volt .8V	age se	etting	g from 2	.4V to					V	[7]/B[7] SH1/VS 17V	= 0, H2 volt	tage set	tingfr	om 9V		C[7] = 0, VSL setting from -9V to -17V
A/B[7:0	0] [ 0	VSH	1/VSH2	2 A/	B[7:0]	VSF	I1/VSF	[2			] VS	H1/VS	H2	A/B[7:0]	VSH1/VSH2	C[7:0] VSL
8Eh	2	2.4		AF	h	5.7				23h	9			3Ch	4	1Ah -9
8Fh	2	2.5		B0	h	5.8				24h	9.2			3Dh	4.2	1Ch -9.5
90h	2	2.6		B1	h	5.9				25h	9.4			3Eh 1	4.4	1Eh -10
91h	2	2.7		B2	h	6				26h	9.6				4.6	20h -10.5
92h	2	2.8		В3	h	6.1				27h	9.8				4.8	22h -11
93h	2	2.9		B4	h	6.2				28h	10				15	24h -11.5
94h	3	3		В5	h	6.3				29h	10.				15.2	26h -12
95h	3	3.1		B6	h	6.4				2Ah	10.				15.4	28h -12.5
96h	3	3.2		B7	'n	6.5				2Bh	10.				15.6	2Ah -13
97h	3	3.3		B8	h	6.6				2Ch	10.	δ			15.8	2Ch -13.5
98h	3	3.4		B9	h	6.7				2Dh 2Eh	11 11.	<u> </u>			16 16.2	2Eh -14 30h -14.5
99h	3	3.5		BA	Ah	6.8				2En 2Fh	11.				16.2 16.4	30h -14.5 32h -15
9Ah	3	3.6		BE	Bh	6.9				30h	11.				10.4 16.6	32h -15.5
9Bh	3	3.7		BC	Ch	7				31h	11.		$\rightarrow$		16.8	36h -16
9Ch	3	3.8		BI	Dh	7.1				32h	11.	0			17	38h -16.5
9Dh	3	3.9		BE	Eh	7.2				33h	12	2			NA	3Ah -17
9Eh	4	4		BF	ĥ	7.3				34h	12.		- i		171	Other NA
9Fh	4	4.1		C0	h	7.4				35h	12.					
A0h	4	4.2		C1	h	7.5				36h	12.					
Alh	4	4.3		C2	h	7.6				37h	13					
A2h	4	4.4		C3	h	7.7				38h	13.	2				
A3h	4	4.5		C4	h	7.8				39h	13.	4				
A4h	4	4.6		C5	h	7.9				3Ah	13.	6				
A5h	4	4.7		C6	h	8				3Bh	13.	8				
A6h	4	4.8		C7	'n	8.1										
A7h	4	4.9		C8	h	8.2										
A8h	5	5		C9	h	8.3										
A9h	5	5.1		CA	Ah	8.4										
AAh	5	5.2		CF	Bh	8.5										Remark:
ABh	5	5.3		CC	Ch	8.6										VSH1>VSH2
ACh	5	5.4		CI	Dh	8.7										
ADh	5	5.5		CE	Eh	8.8										
AEh		5.6		Ot	her	NA										
	0		0F	0	0	0	0	1		1	1	1		e scan start		ning start position of the gate
	1			A7	A6	A5	A4	Ā	۸3	A2	A1	A0	posi	tion	driver. The $A[9:0] = 00$	valid range is from 0 to 679.
	1			0	0	0	0	0	)	0	A9	A8			When TB=( SCN [9:0] = When TB=:	0: = A[9:0]

Commar	nd Table											
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0 0	0	10	0 0	0 0	0 0	1 0	0 0	0 A2	0 A1	0 A0	Deep Sleep mode	Deep Sleep mode Control: A[1:0] : Description 00 Normal Mode [POR]
												00       Normal Mode [POR]         01       Enter Deep Sleep Mode 1         11       Enter Deep Sleep Mode 2         After this command initiated, the chip will         enter Deep Sleep Mode, BUSY pad will         keep output high.         Remark:         To Exit Deep Sleep mode, User required         to send HWRESET to the driver
0	0	11	0	0	0	1	0	0	0	1	Data Entry	Define data entry sequence
0			0	0	0	0	0	A2	AI	A0	mode setting	A[2:0] = 011 [POR] A [1:0] = ID[1:0] Address automatic increment / decrement setting The setting of incrementing or decrementing of the address counter can be made independently in each upper and lower bit of the address. 00 –Y decrement, X decrement, 01 –Y decrement, X decrement, 10 –Y increment, X increment, 11 –Y increment, X increment [POR] A[2] = AM Set the direction in which the address counter is updated automatically after data are written to the RAM. AM= 0, the address counter is updated in the X direction. [POR] AM = 1, the address counter is updated in the Y direction.
0	0	12	0	0	0	1	0	0	1	0	SW RESET	It resets the commands and parameters to their S/W Reset default values except R10h-Deep Sleep Mode During operation, BUSY pad will output high. Note: RAM are unaffected by this command.

Comma	and Table											
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	0	14	0	0	0	1	0	1	0	0	HV Ready Detection	HV ready detection A[6:0] = 00h [POR] The command required CLKEN=1 and ANALOGEN=1. Refer to Register 0x22 for detail. After this command initiated, HV Ready detection starts. BUSY pad will output high during detection. The detection result can be read from the Status Bit Read (Command 0x2F).
0	0	15	0	0	0	1	0	1	0	1	VCI Detection	VCI Detection A[2:0] = 100 [POR], Detect level at 2.3V
0	1		0	0	0	0	0	A2	A1	A0		A[2:0] - 100 [POK], Detect rever at 2.3V A[2:0] : VCI level Detect A[2:0] VCI level 011 2.2V
												100 2.3V
												101 2.4V
												110 2.5V
												111 2.6V
												Other NA
												The command required CLKEN=1 and ANALOGEN=1 Refer to Register 0x22 for detail. After this command initiated, VCI detection starts. BUSY pad will output high during detection. The detection result can be read from the Status Bit Read (Command 0x2F).
)	0	18	0	0	0	1	1	0	0	0	Temperature Sensor Control	Temperature Sensor Selection A[7:0] = 48h [POR], external temperature
0	1		A7	A6	A5	A4	A3	A2	A1	A0		sensor A[7:0] = 80h Internal temperature sensor
)	0	1A	0	0	0	0	0	0	1	0	Temperature Sensor Control (Write to	Write to temperature register. A[11:0] = 7FFh[POR]
0	1		A1 1	A10	A9	A8	A7	A6	A5	A4	temperature register)	
)	1		A3	A2	A1	A0	0	0	0	0		
0	0	1B	0	0	0	1	1	0	1	1	Temperature Sensor Control (Read from	Read from temperature register.
1	1		A1 1	A10	A9	A8	A7	A6	A5	A4	temperature register)	
1	1		A3	A2	A1	A0	0	0	0	0	]	

Comma	ind Table											
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	0	1C	0 A7	0 A6	0 A5	1 A4	1 A3	1 A2	0 A1	0	Temperature Sensor Control (Write	Write Command to External temperature
				-			-			A0	Control (Write Command to External	sensor. A[7:0] = 00h [POR],
0	1		B7 C7	B6 C6	B5 C5	B4 C4	B3 C3	B2 C2	B1 C1	B0 C0	temperature sensor)	$B[7:0] = 00h [POR], \\ C[7:0] = 00h [POR], \\ A[7:6] = 00h [POR], \\ Address + pointer + 1st arameter \\ \hline 01 = Address + pointer + 1st arameter \\ \hline 10 = Address + pointer + 1st arameter \\ \hline 11 = Address \\ A[5:0] - Pointer Setting \\ B[7:0] - 1st parameter \\ C[7:0] - 2nd parameter \\ C[7:0] - 2nd parameter \\ C[7:0] - 2nd parameter \\ The command required CLKEN=1. \\ Refer to Register 0x22 for detail. \\ After this command initiated, Write \\ Command to external temperature sensor \\ starts. BUSY pad will output high during \\ operation. \\ \end{bmatrix}$
0	0	20	0	0	1	0	0	0	0	0	Master Activation	Activate Display Update Sequence The Display Update Sequence Option is located at R22h. BUSY pad will output high during operation. User should not interrupt this operation to avoid corruption of panel images.
0	0	21	0	0	1	0	0	0	0	1	Display Update	RAM content option for Display Update
0	1		A7	A6	A5	A4	A3	A2	Al	A0	Control 1	A[7:0] = 00h [POR]         A[7:4] Red RAM option         0000       Normal         0100       Bypass RAM content as 0         1000       Inverse RAM content         A[3:0]BW RAM option         0000       Normal         0100       Bypass RAM content as 0         1000       Inverse RAM content         0100       Bypass RAM content as 0         1000       Inverse RAM content as 0         1000       Inverse RAM content
0	0	22	0	0	1	0	0	0	1	0	Display Update Control 2	Display Update Sequence Option: Enable the stage for Master Activation
0	1		A7	A6	A5	A4	A3	A2	A1	A0		A[7:0]= FFh (POR)         Parameter (in Hex)         Enable Clock Signal, Then Enable ANALOG         Then DISPLAY with DISPLAY Mode 1         Then Disable ANALOG         Then Disable OSC         Enable Clock Signal,         Then Disable OSC         Enable Clock Signal,         Then Load LUT with         90         DISPLAY Mode 1         Enable Clock Signal,         Then Load Temperature         value from I2C         Single Master Interface         Then Load LUT with



		Enable Clock Signal, Then Load LUT with DISPLAY Mode 2	98
		Enable Clock Signal, Then Load Temperature value from I2C Single Master Interface Then Load LUT with DISPLAY Mode 2	B8
		Enable Clock Signal, Then Load LUT with DISPLAY Mode 1 To Disable Clock Signal	91
		Enable Clock Signal, Then Load Temperature value from I2C Single Master Interface Then Load LUT with DISPLAY Mode 1 To Disable Clock Signal	B1
		Enable Clock Signal, Then Load LUT with DISPLAY Mode 2 To Disable Clock Signal	99
		Enable Clock Signal, Then Load Temperature value from I2C Single Master Interface Then Load LUT with DISPLAY Mode 2 To Disable Clock Signal	В9
		Enable ANALOG Then DISPLAY with DISPLAY Mode 1 Then Disable ANALOG Then Disable OSC	47
		Enable ANALOG Then DISPLAY with DISPLAY Mode 2 Then Disable ANALOG Then Disable OSC	4F
		To Enable Clock Signal	80
		(CLKEN=1) To Enable Clock Signal, then Enable ANALOG (CLKEN=1, ANALOGEN=1)	C0
		Enable ANALOG Then DISPLAY with DISPLAY Mode 1	44
		Enable ANALOG Then DISPLAY with DISPLAY Mode 2	4C
		To DISPLAY with DISPLAY Mode 1	04
		To DISPLAY with DISPLAY Mode 2	0C
		To Disable ANALOG, then Disable Clock Signal (CLKEN=0,	03
		ANALOGEN=0) o Disable Clock Signal (CLKEN=0)	01

Comma	nd Table											
R/W#	D/C#	Hex	D7	D6	D5	D4	D 3	D2	D1	D0	Command	Description
0	0	24	0	0	1	0	0	1	0	0	Write RAM (BW)	After this command, data entries will be written into the BW RAM until another command is written. Address pointers will advance accordingly For Write pixel: Content of Write RAM(BW) = 1 For Black pixel: Content of Write RAM(BW) = 0
0	0	26	0	0	1	0	0	1	1	0	Write RAM (RED)	After this command, data entries will be written into the RED RAM until another command is written. Address pointers will advance accordingly. For Red pixel: Content of Write RAM(RED) = 1 For non-Red pixel [Black or White]: Content of Write RAM(RED) = 0
		27	0	0	1	0	0	1	1	1	D 10414	
0	0	27	0	0	1	0	0	1	1	1	Read RAM	After this command, data read on the MCU bus will fetch data from RAM [According to parameter of Register 41h to select reading RAM(BW) / RAM(RED)], until another command is written. Address pointers will advance accordingly. The 1st byte of data read is dummy data.
0	0	28	0	0	1	0	1	0	0	0	VCOM Sense	Enter VCOM sensing conditions and hold for duration defined in 29h before reading VCOM value. The sensed VCOM voltage is stored in register The command required CLKEN=1 and ANALOGEN=1 Refer to Register 0x22 for detail. BUSY pad will output high during operation.
0	0	29	0	0 A6	0	0	1 A 3	0 A2	0 A1	1 A0	VCOM Sense Duration	Stabling time between entering VCOM sensing mode and reading acquired. A[6]=1, Normal Mode A[6]=0, Reserve A[3:0] = 09h, duration = 10s. VCOM sense duration = Setting + 1 Seconds
0	0	2A	0	0	1	0	1	0	1	0	Program VCOM OTP	Program VCOM register into OTP The command required CLKEN=1. Refer to Register 0x22 for detail. BUSY pad will output high during operation.

Comma	nd Table	;														
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Descripti	on			
0	0	2B	0	0	1	0	1	0	1	1	Write Register for		mand is us			
0	1	1	0	0	0	0	0	1	0	0	VCOM Control	when ACVCOM toggle. Two data bytes D04h and D63h should be set for this				
0	1		0	1	1	0	0	0	1	1		command				
	L	1						1				1				
0	0	2C	0 A7	0 A6	1 A5	0 A4	1 A3	1 A2	0 A1	0 A0	Write VCOM register	Write VC A[7:0] =	COM regist 00h [POR]	er from M	CU interface	
0	1		A/	A0	AS	A4	AS	A2	AI	AU		A[7:0]	VCOM	A[7:0]	VCOM	
												08h	-0.2	58h	-2.2	
												0Ch	-0.3	5Ch	-2.3	
												10h	-0.4	60h	-2.4	
												14h	-0.5	64h	-2.5	
												14h	-0.6	68h	-2.6	
												10h	-0.0	6Ch	-2.7	
												20h	-0.7	70h	-2.7	
												20h	-0.8	70h 74h	-2.8	
												24h 28h	-1	78h	-3	
												20h	-1.1	70h	-3.1	
												30h	-1.2	80h	-3.2	
												30h 34h	-1.2	84	-3.2	
												34h 38h	-1.4	88	-3.4	
												3Ch	-1.5	8C	-3.5	
												40h	-1.6	90	-3.6	
												40h 44h	-1.0	90	-3.7	
												44li 48h	-1.8	94	-3.8	
												40h	-1.9	96 9C	-3.9	
												50h	-1.9	A0	-3.9	
												54h	-2.1	AU	-4	
												5411	-2.1			
0	0	2D	0	0	1	0	1	1	0	1	OTP Register Read for	Read Rea	gister for D	isplay Opt	ion:	
1	1		A7	A6	A5	A4	A3	A2	Al	A0	Display Option	A[7:0]: V	COM OTI	P Selection		
1	1		B7	B6	B5	B4	B3	B2	B1	B0	4		nd 0x37, By COM Reg			
1	1		Б7 С7	C6	C5	C4	C3	C2	C1	C0	-	(Commai		15101		
1	1		D7	D6	D5	D4	D3	D2	D1	D0	-	C[7:0]~G	[7:0]: Disp	lay Mode		
1	1		E7	E6	E5	E4	E3	E2	E1	E0	-	(Commai [5 bytes]	nd 0x37, By	te B to By	rte G)	
1	1										4	H[7:0]~K	[7:0]: Way	eform Ve	rsion	
			F7	F6	F5	F4	F3	F2	F1	F0		(Comman	nd 0x37, By	te H to By	/te K)	
1	1		G7	G6	G5	G4	G3	G2	G1	G0	-	[4 bytes]				
1	1		H7	H6	H5	H4	H3	H2	H1	H0	4					
1	1		I7	I6	15	I4	13	I2	I1	10	-					
1	1		J7	J6	J5	J4	J3	J2	J1	JO	-					
1	1		K7	K6	K5	K4	K3	K2	K1	K0						

	and Table		D7	D/	D5	D4	D	D	D1	DA	Comment	Description				
R/W#	D/C#	Hex 34	D7 0	D6 0	D5 1	D4 1	D3 0	D2 1	D1 0	D0 0	Command CRC calculation	Description CRC calculation command for OTP content validation. BUSY pad will output high during operation.				
												operation.				
0	0	35	0	0	1	1	0	1	0	1	CRC Status Read	CRC Status Read				
		55	-				Al		-	-	-	A[15:0] is the CRC readout Value				
1	1		A15	A14	A13	A12	1	A10	A9	A8	-					
1	1		A7	A6	A5	A4	A3	A2	A1	A0						
0		24	<u>^</u>	0			<u>^</u>									
0	0	36	0	0	1	1	0	1	1	0	Program OTP selection	Program OTP Selection according to OTP Selection Control [R37h ar R38h] The command required CLKEN=1. Refer to Register 0x22 for detail. BUSY pad will output high during operation.				
	•		-	-		-										
0	0	37	0	0	1	1	0	1	1	1	Write Register for Display Option	Write Register for Display Option B[7:0] Display Mode for WS[7:0]				
0	1		0	0	0	0	0	0	0	0	Display Option	C[7:0] Display Mode for WS[15:8]				
0	1		B7	B6	B5	B4	B3	B2	B1	B0		D[7:0] Display Mode for WS[23:16] E[7:0] Display Mode for WS[31:24]				
0	1		C7	C6	C5	C4	C3	C2	C1	C0		F[3:0] Display Mode for WS[35:32]				
0	1		D7	D6	D5	D4	D3	D2	D1	D0		0: Display Mode 1 1: Display Mode2 F[6]: PingPong for Display Mode 2				
0	1		E7	E6	E5	E4	E3	E2	E1	EO						
0	1		F7	F6	F5	F4	F3	F2	F1	F0	-	F[7]: PingPong for Display Mode 1				
0	1		G7	G6	G5	G4	G3	G2	G1	G0	-	1: Ping-Pong 0: Default G[7:0]~J[7:0] module ID /waveform version.				
0	1		H7	H6	H5	H4	H3	H2	H1	H0	-					
0	1		I7	16	15	I4	-13	12	I1	10	-	Remarks: A[7:0]~J[7:0] can be stored				
0	1		J7	J6	J5	J4	J3	J2	J1	JO		OTP				
0	0	38	0	0	1	1	1		0	0	Write Register for	Write Register for User ID				
0	1	50	0	0	1	1	1	0	0	0	User	A[7:0]]~J[7:0]: UserID [10 bytes]				
0	1		A7 B7	A6	A5	A4	A3	A2 P2	A1 D1	A0 P0	ID	Remarks: A[7:0]~J[7:0] can be stored OTP				
0	1		В7 С7	B6 C6	В5 С5	B4 C4	B3 C3	B2 C2	B1 C1	В0 С0	4	011				
0	1		D7	C6 D6	D5	D4	D3	D2	D1	D0	4					
0	1		E7	E6	E5	E4	E3	E2	E1	E0	4					
0	1		E7 F7	F6	F5	F4	F3	F2	F1	F0	1					
0	1		G7	G6	G5	G4	G3	G2	G1	G0	4					
0	1		H7	H6	H5	H4	H3	H2	H1	H0	_					
0	1		I7	110 16	115	I4	I3	I12 I2	II II	110 10						
0	1		J7	10 J6	15 J5	J4	J3	J2	J1	JO	4					

	nd Table	**	7.5	D.	<b>D</b> 4	54		DA	DI	Dû	a .			
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description		
)	0	3A	0	0	1	1	1	0	1	0	Reserved	Reserved		
	•											•		
)	0	3B	0	0	1	1	1	0	1	1	Reserved	Reserved		
)	0	3C	0	0	1	1	1	1	0	0	Border Waveform	Select border waveform for VBD		
)	1		A7	A6	A5	A4	0	0	A1	A0	Control	$\begin{array}{c c} A[7:0] = C0h [POR], set VBD as HIZ. \\ A [7:6] :Select VBD option \\\hline A[7:6] Select VBD as \\\hline 00 & GS Transition, \\ & Defined in A[1:0] \\\hline 01 & Fix Level, \\ & Defined in A[5:4] \\\hline 10 & VCOM \\\hline 11[POR] & HiZ \\\hline A [5:4] Fix Level Setting for VBD \\\hline A[5:4] Fix Level Setting for VBD \\\hline A[5:4] & VBD level \\\hline 00[POR] & VSS \\\hline 01 & VSH1 \\\hline 10 & VSL \\\hline 11 & VSH2 \\\hline A [1:0] GS Transition setting for VBD \\\hline A[1:0] & VBD Transition \\\hline 00[POR] & LUT0 \\\hline 01 & LUT1 \\\hline \end{array}$		
												10         LUT2           11         LUT3		
)	0	41	0	1	0	0	0	0	0	1	Read RAM Option	Read RAM Option A[0]= 0 [POR]		
	1		0	0	0	0	0	0	0	A0		0: Read RAM corresponding to 24h 1: Read RAM corresponding to 26h		
)	0	44	0	1	0	0	0	1	0	0	Set RAM X - address	Specify the start/end positions of the		
)	1		A7	A6	A5	A4	A3	A2	A1	A0	Start / End position	window address in the X direction by an address unit for RAM		
)	1		-	-	-	-		-	A9	A8		address unit for RAM A[9:0]: XSA[9:0], XStart, POR = 000h B[5:0]: XEA[9:0], XEnd, POR = 3BFh		
)	1		0	0	B5	B4	B3	B2	B1	B0	-			
)	1		-	-	-	-	-	-	B9	B8	1			

Comma	and Table											
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	0	45	0	1	0	0	0	1	0	1	Set RAM Y-	Sussify the start/and use iting a fithe
0	1		A7	A6	A5	A4	A3	A2	A1	A0	address Start / End	Specify the start/end positions of the window address in the Y direction by an
0	1		-	-	-	-	-	-	A9	A8	position	address unit for RAM
0	1		B7	B6	B5	B4	B3	B2	B1	B0		A[8:0]: YSA[8:0], YStart, POR = 000h
0	1		-	-	-	-	-	-	B9	B8		B[8:0]: YEA[8:0], YEnd, POR = 2A7h
				1	1	1				l	1	
0	0	46	0	1	0	0	0	1	1	0	Auto Write RED	Auto Write RED RAM for Regular Pattern
0	1		A7	A6	A5	A4	0	A2	Al	A0	RAM for Regular Pattern	A[7:0] = 00h [POR]         A[7]: The 1st step value, POR = 0         A[6:4]: Step Height, POR= 000         Step of alter RAM in Y-direction according to Gate $\overline{A[6:4]}$ $\overline{A[6:4]}$ Height       A[6:4]         Height       A[6:4]         Height       A[6:4] $\overline{000}$ 8 $\overline{001}$ 16 $\overline{001}$ 16 $\overline{010}$ 32 $\overline{011}$ 64 $\overline{011}$ 64 $\overline{011}$ 64 $\overline{011}$ 64 $\overline{012}$ Width $\overline{010}$ 128 $\overline{001}$ 16 $\overline{010}$ 128 $\overline{000}$ 8 $\overline{000}$ 8 $\overline{000}$ 16 $\overline{010}$ 1256 $\overline{010}$ 32 $\overline{011}$ 64
												operation.
0	0	47	0	1	0	0	0	1	1	1	Auto Write B/W	Auto Write B/W RAM for Regular Pattern
0	1	4/	A7	A6	A5	A4	A3	A2	A1	A0	Auto write B/w RAM for Regular Pattern	Auto Write B/W RAM for Regular Pattern $A[7:0] = 00h$ [POR]         Auto Write B/W RAM for Regular Pattern $A[7:0] = 00h$ [POR] $A[6:4]$ Height $A[2:0]$ :       Step Width, POR=000         Step of alter RAM in X-direction according to Source $A[2:0]$ Width $A[2:0]$ Uith $A[2:0]$ Width $A[2:0]$ Uith $A[2:0]$ Width

Comm	and Table	e												
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description		
0	0	4E	0	1	0	0	1	1	1	0	Set RAM X	Make initial settings for the RAM X		
0	1		A7	A6	A5	A4	A3	A2	A1	A0	address	address in the address counter (AC)		
0	1		0	0	0	0	0	0	A9	A8	counter	A[9:0]: 000h [POR].		
		•		•	•			•			•			
0	0	4F	0	1	0	0	1	1	1	1	Set RAM Y	Make initial settings for the RAM Y		
0	1		A7	A6	A5	A4	A3	A2	A1	A0	address	address in the address counter (AC)		
0	1		0	0	0	0	0	0	A9	A8	counter	A[9:0]: 000h [POR].		
		•			•			•			·			
0	0	7F	0	1	1	1	1	1	1	1	NOP	This command is an empty command; it does not have any effect on the display module. However, it can be used to terminate Frame Memory Write or Read Commands.		

# 6. Optical characteristics

# 6.1 Specifications

Measurements are made with that the illumination is under an angle of 45 degrees, the detection is perpendicular unless otherwise specified.

T=25	°C
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SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР.	MAX	UNIT	Note
R	Reflectance	White	30	35	-	%	Note 6.1-1
Gn	2Grey Level	-	-	DS+(WS-DS)×n(m-1)	-	L*	-
CR	Contrast Ratio	-	10	15	-		-
DC	Dark State L* value		-	13	14		Note 6.1-1
DS	Dark State a* value		-	3	5		Note 6.1-1
WS	White State L* value		63	65	-		Note 6.1-1
DC	Red State L* value	Red	25	28	-		Note 6.1-1
RS	Red State a* value	Red	36	40	-		Note 6.1-1
Panel's life	-	0°C~40°C		5years	-	-	Note 6.1-2
Denal	Image Update	Storage and transportation	-	Update the white screen	-	-	-
Panel	Update Time	Operation	-	Suggest Updated once a day	-	-	-

WS : White state, DS : Dark state, RS: Red state

Note 6.1-1 : Luminance meter : Eye - One Pro Spectrophotometer Note 6.1-2 :We don't guarantee 5 years pixels display quality for humidity below 45%RH or above 70%RH;

Suggest Updated once a day;



### 6.2 Definition of contrast ratio

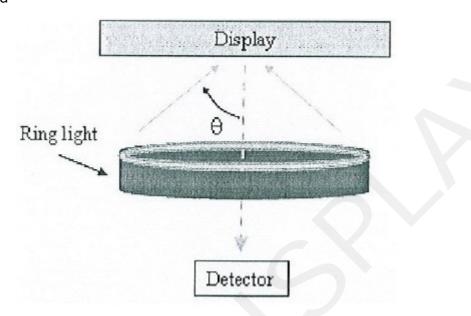
The contrast ratio (CR) is the ratio between the reflectance in a full white area (R1) and the reflectance in a dark area (Rd)() :

R1: white reflectance

CR = R1/Rd

Rd: dark reflectance

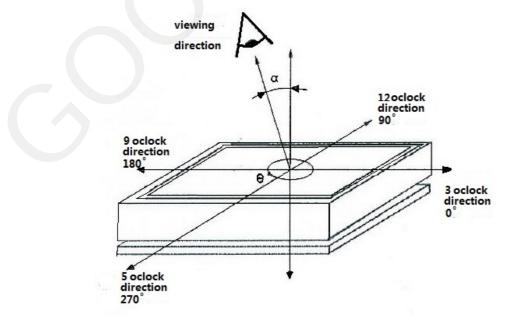




### 6.3 Reflection Ratio

The reflection ratio is expressed as :

R = Reflectance Factor white board x (L center / L white board )L center is the luminance measured at center in a white area (R=G =B=1). L white board is the luminance of a standard white board. Both are measured with equivalent illumination source. The viewing angle shall be no more than 2 degrees .

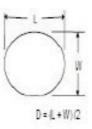


# 7. Point and line standard

		Shipment Ins	pection Standard	l							
	Ec	quipment: Electric	al test fixture, Point gau	ge							
Outline dimension	170.2(H)×111.2(V) ×1.25(D)	Unit: mm	Part-A	Active area	Part-B	Border area					
<b>F</b>	Temperature	Humidity	Illuminance	Distance	Time	Angle					
Environment	19℃~25℃	55%±5%RH	800~1300Lux	300mm	35Sec						
Defet type	Inspection method	S	Standard	Part-	A	Part-B					
		Ι	D≤0.2mm	Igno	re	Ignore					
Spot		0.2m	n <d≤0.4mm< td=""><td>N≤₄</td><td>4</td><td>Ignore</td></d≤0.4mm<>	N≤₄	4	Ignore					
	Electric Display	0.4m	n <d≤0.6mm< td=""><td>N≤</td><td>Ignore</td></d≤0.6mm<>	N≤	Ignore						
		E	0>0.6mm	Not Al	Not Allow						
Display unwork	Electric Display	N	ot Allow	Not Allow Ign		Ignore					
Display error	Electric Display	N	ot Allow	Not Al	low	Ignore					
Scratch or line		L≤2m	m, W≤0.1mm	Igno	re	Ignore					
defect(include	Visual/Film card	1.0mm <l≤9.0< td=""><td>mm, 0.1&lt;₩≤0.2mm,</td><td>NS</td><td colspan="3">N≤2</td></l≤9.0<>	mm, 0.1<₩≤0.2mm,	NS	N≤2						
dirt)		L>9.0r	nm, W>0.2mm	Not Al	Not Allow						
		D	≥0.4mm	Igno	Ignore						
PS Bubble	Visual/Film card	0.4mr	n≤D≤0.6mm	N≤₄	Ignore						
		D	>0.6 mm	Not Al	Not Allow						
Side Fragment	Do not affect the electrode circuit( (Corner chipping)         X≤8mm, Y≤1mm, Do not affect the electrode circuit,         Ignore										
		1.Cannot be defea	ct & failure cause by app	bearance defect;							
Remark		2.Cannot be la	rger size cause by appea	rance defect;							
		L=long W=	=wide D=point size N	=Defects NO							



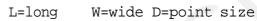




L = L1 + L2

Line Defect

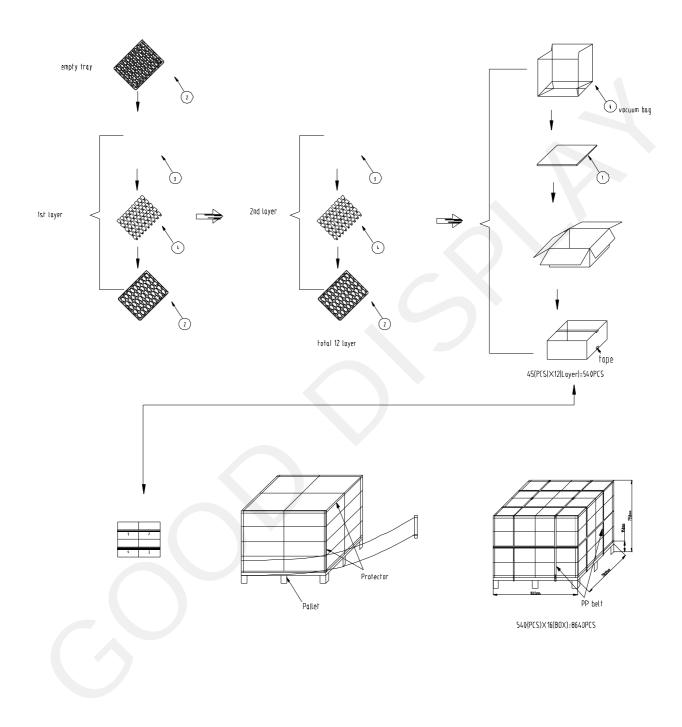
Spot Defect



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# 8. Packing



### 9. Precautions

- (1) Do not apply pressure to the EPD panel in order to prevent damaging it.
- (2) Do not connect or disconnect the interface connector while the EPD panel is in operation.
- (3) Do not touch IC bonding area. It may scratch TFT lead or damage IC function.
- (4) Please be mindful of moisture to avoid its penetration into the EPD panel, which may cause damage during operation.
- (5) If the EPD Panel / Module is not refreshed every 24 hours, a phenomena known as "Ghosting" or "Image Sticking" may occur. It is recommended to refreshed the ESL /EPD Tag every 24 hours in use case. It is recommended that customer ships or stores the ESL / EPD Tag with a completely white image to avoid this issue
- (6) High temperature, high humidity, sunlight or fluorescent light may degrade the EPD panel's performance. Please do not expose the unprotected EPD panel to high temperature, high humidity, sunlight, or fluorescent for long periods of time.
- (7) For more precautions, please click on the link:
   http://www.good-display.com/news/Precautions-for-E-paper-Display-80.html